

April 2010

FAN5340 Synchronous Constant-Current Series Boost LED Driver with PWM Brightness Control and Integrated Load Disconnect

Features

- Synchronous Current-Mode Boost Converter
- Up to 500mW Output Power
- Supports 2, 3, or 4 LEDs in Series
- 2.7V to 4.8V Input Voltage Range
- 1.2MHz Fixed Switching Frequency
- 1mA Maximum Quiescent Current
- Soft-Start Capability
- Input Under-Voltage Lockout (UVLO)
- Output Over-Voltage Protection (OVP)
- Short-Circuit Detection
- Thermal Shutdown (TSD) Protection
- 8-Lead 3.00 x 3.00mm MLP
- 8-Bump 1.57 x 1.57mm WLCSP

Applications

- Cellular Phones, Smart Phones
- Pocket PCs
- WLAN DC-DC Converter Modules
- PDA, DSC, PMP, and MP3 Players

Description

The FAN5340 is a synchronous constant-current LED driver capable of efficiently delivering up to 500mW to a string of up to four LEDs in series. Optimized for small form-factor applications, the 1.2MHz fixed switching frequency allows the use of chip inductors and capacitors.

For safety, the device features integrated short-circuit detection plus over-voltage and thermal shutdown protections. In addition, input under-voltage lockout protection is triggered if the battery voltage is low.

Brightness (dimming) control is implemented by applying a PWM signal of 300Hz to 1kHz on the EN pin. During shutdown, the FAN5340 disconnects the LED anodes from the output of the boost regulator, which holds the boost regulator's voltage on C_{OUT} , reducing audible noise from the PWM dimming and removing power from the LED string.

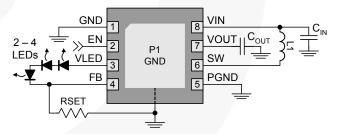


Figure 1. Typical Application

Ordering Information

Part Number	Operating Temperature Range	Package	Packing
FAN5340UCX	-40 to 85°C	8-Bump, 1.57 x 1.57mm Wafer Level Chip-Scale Package (WLCSP)	Tape and Reel
FAN5340MPX (Prelminary)	-40 to 85°C	8-Lead, 3.00 x 3.00mm Molded Leadless Package (MLP)	Tape and Reel

Block Diagrams

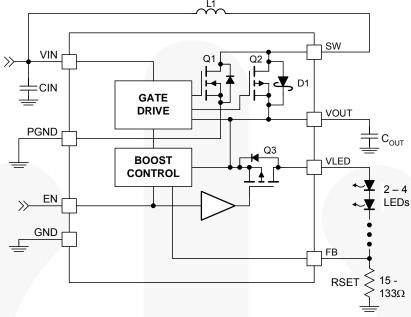


Figure 2. Block Diagram

Table 1. Recommended External Components

Component	Description	Vendor	Parameter	Min.	Тур.	Max.	Units
L1	22. II Naminal	Murata	L ⁽¹⁾		22		μΗ
LI	22μH Nominal	LQH3NPN220MGOK	DCR (Series R)		1100		mΩ
C_{OUT}	4.7μF X5R or Better		С		4.7		μF
C _{IN}	4.7μF X5R or Better		С		4.7		μF

Note:

1. Minimum L (inductance) incorporates tolerance, temperature, and DC bias effects (L decreases with increasing current).

Pin Configuration

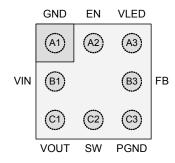


Figure 3. WLCSP Package, Top View

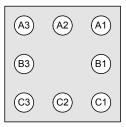


Figure 4. WLCSP Package, Bottom View

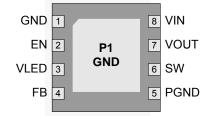


Figure 5. 8-Pin 3 x 3mm MLP, Top View

Pin Definitions

Pir	า #	Name	Description		
CSP	MLP	Name	Description		
A1	1	GND	Analog Ground. All signals are referenced to this pin.		
A2	2	EN	Enable / PWM Brightness Control . A logic LOW on this pin shuts down the IC, disconnects the LEDs from VOUT, and reduces the current consumption of the IC. This terminal has an internal pull-down resistor of $300k\Omega$.		
A3	3	VLED	LED String Output. Connected to the anode of a series string of two to four LEDs.		
ВЗ	4	FB	Current Feedback . The boost regulator regulates this pin to 0.5V to control the LED string current. Tie this pin via a current-setting resistor (R_{SET}) to GND and the cathode of the LED string.		
C3	5	PGND	Power Ground. The boost switch and gate drivers are grounded at this pin.		
C2	6	SW	Switching Node. Tie inductor L1 from V _{IN} to this pin.		
C1	7	VOUT	Boost Output Voltage. Output of the boost regulator.		
B1	8	VIN	Input Voltage.		

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Parameter			
V _{IN}	VIN		-0.3	6.0	V
V_{FB}, V_{EN}	FB, EN Pins		-0.3	V _{IN} + 0.3	V
V_{SW}	SW Pin		-0.3	24.0	V
V _{OUT}	VOUT Pin		-0.3	24.0	V
ESD	Electrostatic Discharge	Human Body Model per JESD22-A114	4.0		kV
ESD	Protection Level	Charged Device Model per JESD22-C101	1	.5	ΚV
TJ	Junction Temperature		-40	+150	°C
T _{STG}	Storage Temperature		-65	+150	°C
TL	Lead Soldering Temperature, 10	Lead Soldering Temperature, 10 Seconds		+260	°C

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Тур.	Max.	Units
V _{IN}	VIN Supply Voltage	2.7		4.8	V
V _{OUT}	VOUT Voltage	6.2		16.0	V
I _{OUT}	VOUT Load Current	5		40	mA
f _{EN_PWM}	EN pin PWM Dimming Frequency	100	300	1000	Hz
T _A	Ambient Temperature	-40		+85	°C
TJ	Junction Temperature	-40		+125	°C

Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer 2s2p evaluation boards in accordance to JEDEC standard JESD51. Special attention must be paid not to exceed junction temperature $T_{J(max)}$ at a given ambient temperate T_A .

Symbol	Paramete	Parameter		
	lunction to Ambient Thomas Decistores	WLCSP Package	110	°C/W
$\theta_{\sf JA}$	Junction-to-Ambient Thermal Resistance	MLP Package	49	°C/W

Electrical Specifications

 V_{IN} = 2.7V to 4.8V and T_A = -40°C to +85°C unless otherwise noted. Typical values are at T_A = 25°C and V_{IN} = 3.6V.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Power Sup	oplies					•
IQ	Quiescent Current	EN = V _{IN} , Device Not Switching			1	mA
I _{SD}	Shutdown Supply Current	EN = GND, V _{IN} = 3.6V		0.3	1.0	μΑ
\/	Linder Voltage Leekeut	V _{IN} Rising	2.30	2.40	2.50	V
V_{UVLO}	Under-Voltage Lockout	V _{IN} Falling	2.00	2.15	2.25	V
V _{UVHYST}	Under-Voltage Lockout Hysteresis			250		mV
EN: Enabl	e Pin					
V_{IH}	HIGH-Level Input Voltage		1.2			V
V_{IL}	LOW-Level Input Voltage				0.4	V
R_{EN}	EN Pull-Down Resistance		200	300	400	kΩ
t _{SD}	EN Low to Shutdown Delay	From Falling Edge of EN	20		80	ms
Feedback	and Reference					
V_{FB}	Feedback Voltage		480	500	520	mV
I _{FB}	Feedback Input Current	V _{FB} = 500mV		0.1	1.0	μΑ
Power Ou	tputs					
В	Boost Switch On-Resistance	V _{IN} = 3.6V, V _{OUT} = 10V, I _{SW} = 100mA		600		
R _{DS(ON)_Q1}		V _{IN} = 2.7V, V _{OUT} = 10V, I _{SW} = 100mA		850		mΩ
R _{DS(ON)_Q2}	Synchronous Rectifier On-Resistance	V _{OUT} = 10V, I _{SW} = 100mA		2.0		Ω
R _{DS(ON)_Q3}	Load Switch On-Resistance	V _{OUT} = 10V, I _{LED} = 10mA		2.8		Ω
I _{SW(OFF)}	SW Node Leakage ⁽²⁾	$EN = 0$, $V_{IN} = V_{SW} = V_{OUT} = 5.5V$, $V_{LED} = 0$		0.1	1.0	μА
I _{LIM-PK}	Boost Switch Peak Current Limit	V _{IN} = 3.6V	325	400	475	mA
Oscillator				-1		
f _{SW}	Boost Regulator Switching Frequency		1.0	1.2	1.4	MHz
PWM Dim	ming			-		•
D _{PWM}	PWM Duty Cycle ⁽³⁾	PWM Dimming Frequency ≤1kHz	1.0		100	%
Output an	d Protection					
V _{OVP}	Boost Output Over-Voltage Protection		18.0	19.0	20.0	V
V _{OVPHYST}	OVP Hysteresis			0.8		V
\/	V Chart Circuit Detection Thereby	V _{OUT} Falling		V _{IN} - 1.5		V
V_{THSC}	V _{LED} Short-Circuit Detection Threshold	V _{OUT} Rising		V _{IN} - 1.3		V
D _{MAX}	Maximum Boost Duty Cycle ⁽³⁾		85			%
D _{MIN}	Minimum Boost Duty Cycle ⁽³⁾				20	%
T _{SD}	Thermal Shutdown			150	/1 /	°C
T _{HYS}	Thermal Shutdown Hysteresis			25		°C

Notes:

- 2. SW leakage current includes the leakage current of three internal switches; SW to GND, V_{OUT} to V_{LED}, and SW to V_{OUT}.
- 3. Guaranteed by design.

Typical Characteristics

 V_{IN} = 3.6V, T_A = 25°C, I_{LED} = 20mA, L = 22 μ H, C_{OUT} = 4.7 μ F.

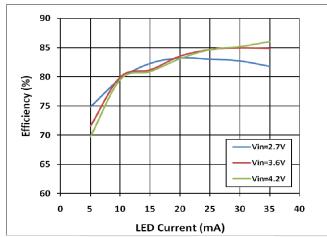


Figure 6. Efficiency vs. LED Current: Two LEDs

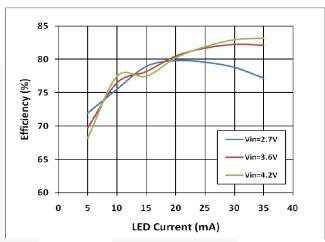


Figure 7. Efficiency vs. LED Current: Three LEDs

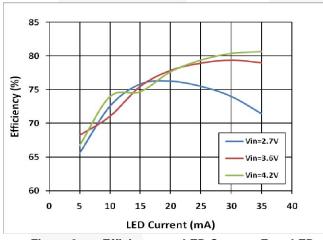


Figure 8. Efficiency vs. LED Current: Four LEDs

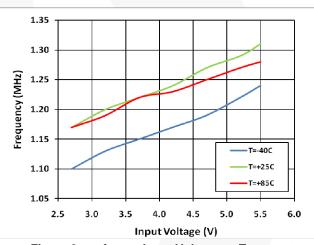


Figure 9. f_{SW} vs. Input Voltage vs.Temperature

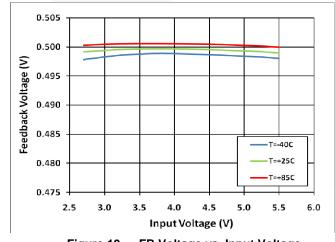


Figure 10. FB Voltage vs. Input Voltage vs. Temperature

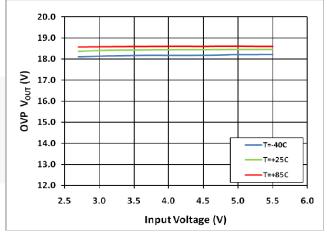


Figure 11. OVP vs. Input Voltage vs. Temperature

Typical Characteristics (Continued)

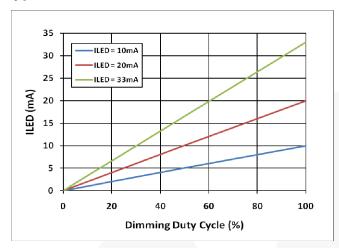
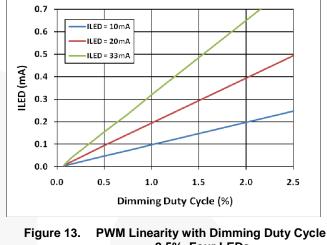
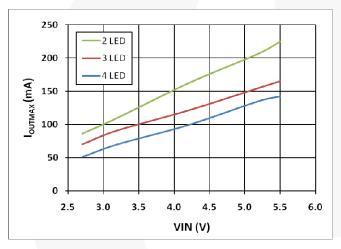


Figure 12. **PWM Linearity Over Full Dimming Duty** Cycle Range, Four LEDs



<2.5%, Four LEDs



Maximum Output Current at Vout

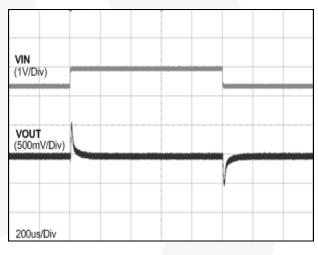
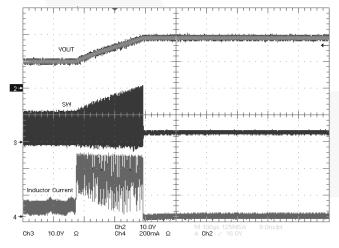


Figure 15. Line Transient with 10µs Line Step, **Four LEDs**



Over-Voltage Protection: Soft-Start into Figure 16. **Open LED String**

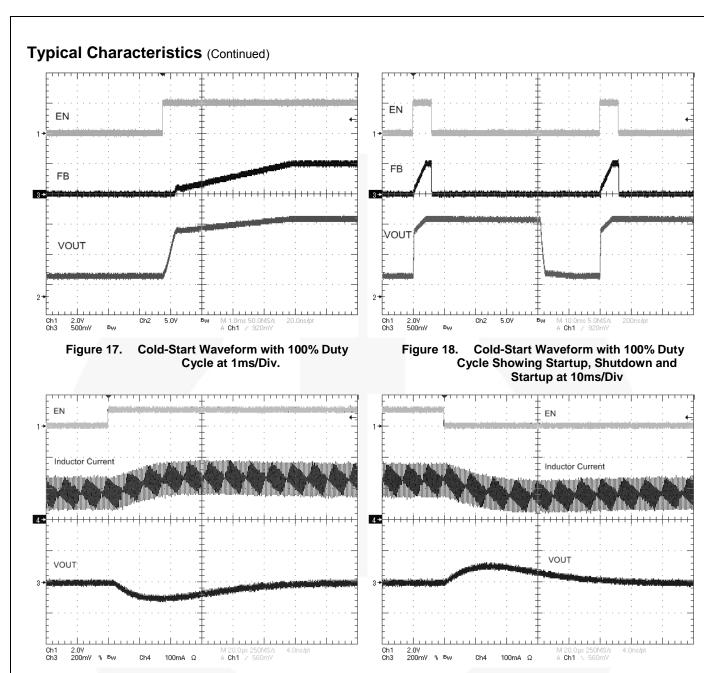


Figure 19. FAN5340 I_{LOAD} Step from 20mA to 30mA by Enabling FAN5640 at 10mA, Three LEDs

Figure 20. FAN5340 I_{LOAD} Step from 30mA to 20mA by Disabling FAN5640 at 10mA, Three LEDs

Circuit Description

Overview

The FAN5340 is an inductive current-mode boost serial LED driver that achieves LED current regulation by maintaining 0.5V across R_{SET} . The current through the LED string (I_{LED}) is therefore:

$$I_{LED} = \frac{0.5}{R_{SET}} \tag{1}$$

While the forward-voltage across the LEDs determines V_{OUT} , the FAN5340's boost regulator output can also support additional loads on V_{OUT} (see Figure 21) provided its input current limit is not exceeded.

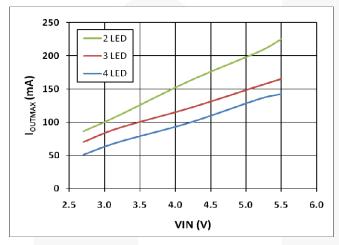


Figure 21. Maximum Output Current vs. Input Voltage

UVLO and Soft-Start

If EN has been LOW for more than 20ms, the IC initiates a "cold start" soft-start cycle when EN rises, provided V_{IN} is above the UVLO threshold. The soft-start circuit ramps the voltage reference to the error amplifier to control inrush current.

PWM Dimming

When EN goes LOW, the IC turns off a MOSFET (Q3 in Figure 2), which disconnects the LED load, preventing C_{OUT} from being discharged when EN is LOW. As long as EN is low for less than 20ms, the regulator's main regulation loop quickly regains control when EN returns to a HIGH state.

Short-Circuit Detection

If V_{OUT} falls below $V_{IN}-1.5V,\ Q3$ turns off and remains off until V_{OUT} recovers to at least $V_{IN}-1.3V.$

Over-Voltage Protection

If the LED string is open circuit, FB remains at 0V and the output voltage continues to increase in the absence of an Over-Voltage Protection (OVP) circuit. The FAN5340's OVP circuit disables the boost regulator when V_{OUT} exceeds 19.0V and continues to keep the regulator off until V_{OUT} drops below 18.2V.

Thermal Shutdown

If the die temperature exceeds 150°C, a reset occurs and remains in effect until the die cools to 125°C, at which time the circuit is allowed to begin the soft-start sequence.

Applications

Using VOUT to Drive Additional LED Strings

The VOUT pin can be used as a supply for simple current sources (shown in Figure 22 using the FAN5640) or discrete current sinks. To avoid dragging V_{OUT} down when the EN pin is LOW, the auxiliary strings should not be enabled unless the EN pin is HIGH. The auxiliary strings can therefore be PWM dimmed using either the same line as the EN line as shown below or enabled separately, but within the on-time of the FAN5340.

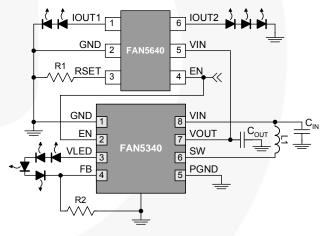
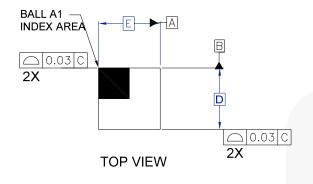
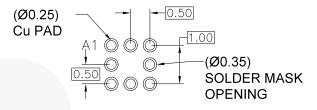


Figure 22. Driving Additional LED Strings

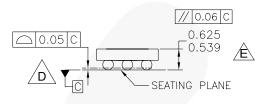
If using VOUT to drive additional loads, care should be taken not to exceed the input current limit. This limitation is shown in Figure 21 for a typical IC. The total load ($I_{\rm OUT}1 + I_{\rm OUT}2 + I_{\rm LED}$) should always remain below 70% of the value in Figure 21.

Physical Dimensions





RECOMMENDED LAND PATTERN (NSMD)





SIDE VIEWS

NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C, DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994
- DATUM C, THE SEATING PLANE, IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- E. PACKAGE TYPICAL HEIGHT IS 582 MICRONS ± 43 MICRONS (539-625 MICRONS).



- G. BALL COMPOSITION: Sn95.5-Ag3.9-Cu0.6
- I. DRAWING FILENAME: MKT-UC008ABrev2.

Product-Specific Dimensions

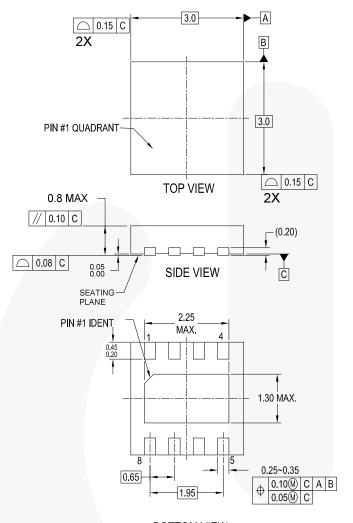
Product	D	E	X	Υ
FAN5340UC	1.570	1.570	0.285	0.285

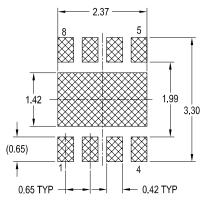
Figure 23. 8-Bump, 1.57 x 1.57mm Wafer Level Chip-Scale Package (WLCSP)

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Physical Dimensions (Continued)





RECOMMENDED LAND PATTERN

NOTES: BOTTOM VIEW

A. CONFORMS TO JEDEC REGISTRATION MO-229, VARIATION VEEC, DATED 11/2001

- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994
- D. FILENAME: MKT-MLP08Drev2

Figure 24. 8-Pin, 3 x 3mm Molded Leadless Package (MLP)

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SuperSOTTM-8
SuperSOTTM-8
SuperSOTTM-8
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Datasheet Identification	Product Status	Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
UNITED AND THE RESIDENCE OF THE PROPERTY OF T		Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

Rev. 148